Amendments to the Claims

of said driving signal (215).

1. (Cancelled)
2. (Cancelled)
3. (Currently Amended) The linear power amplifier as claimed in Claim 2,
A radio frequency (RF) linear power amplifier (200) operating in an output frequency
band, having an output transistor (Q2), said power amplifier comprising: (a) a circuit
means (300') for generating a bias signal producing a quiescent current flowing
through said output transistor (42) of said RF power amplifier,
b) a detector circuit means (210) for detecting RF input to said amplifier and
generating a driving signal (215) according to a power level of said RF input;
(c) a self-adapting circuit means (250) for receiving said driving signal (215)
and automatically modifying said bias signal and said quiescent current through said
output transistor (Q2), whereby said quiescent current at said output stage is adjusted
for reduced dissipation and increased linearity at all power output levels; and

signal being input to the amplifier at power ranges above a certain power output threshold; and _______wherein the detector circuit means (210) for generating said driving signal (215) is connected to said self adapting circuit means (250), said self adapting circuit means further including means (211.212) for filtering out any RF component

said quiescent current for an output stage amplifier by tracking said detected RF

wherein the self-adapting circuit means (250) automatically modifies

4. (Currently Amended) The linear power amplifier as claimed in Claim 2. The linear power amplifier as claimed in Claim3, wherein the self adapting circuit means (250) includes means (225,228) for automatically reducing the quiescent current for an output stage amplifier from one state of lower quiescent current to another state of higher quiescent current.

5. (Currently Amended) The linear power amplifier as elaimed in Claim 1, The linear power amplifier as claimed in Claim 3, comprising first and second power output stages, wherein said detector circuit means (210) detects RF input to said amplifier at said first output stage (Q1), for reducing said quiescent current at a second output stage (O2).

6. (Currently Amended) The linear newer amplifier as claimed in Claim 1. A radio frequency (RF) linear power amplifier (200) operating in an output frequency band, having an output transistor (O2), said power amplifier comprising: (a) a circuit means (300') for generating a bias signal producing a quiescent current flowing through said output transistor (42) of said RF power amplifier. b) a detector circuit means (210) for detecting RF input to said amplifier and generating a driving signal (215) according to a power level of said RF input; (c) a self-adapting circuit means (250) for receiving said driving signal (215) and automatically modifying said bias signal and said quiescent current through said output transistor (O2), whereby said quiescent current at said output stage is adjusted for reduced dissipation and increased linearity at all power output levels; and further comprising means (125,126) (d) means (125,126) for further modifying said quiescent current at a second output stage under discrete voltage control. 7. (Cancelled) 8. (Cancelled) 9. (Currently Amended) The device as claimed in Claim 7, A device including a radio frequency linear power amplifier operating in an output frequency band, having an output transistor, said power amplifier comprising: (a) a circuit means (300') for generating a bias signal producing a quiescent current flowing through said output transistor (42) of said RF power amplifier: (b) a detector circuit means (210) for detecting RF input to said amplifier and

generating a driving signal (215) according to a power level of said RF input;

Appl. No. 10/538,347; Docket No. US02 0584 Amdt. dated April 17, 2007 Response to Office Action dated January 17, 2007 (c) a self-adapting circuit means (250) for receiving said driving signal (215) and automatically modifying said bias signal and said quiescent current through said output transistor (O2), whereby said quiescent current at said output stage is adjusted for reducted dissipation and increased linearity at all power output levels; and wherein the detector circuit means (210) for generating said driving signal (215) is connected to said self adapting circuit means, said self adapting circuit further including means (211,212) for filtering out any RF component of said driving signal. 10. (Currently Amended) The device as claimed in Claim 7. The device as claimed in Claim 9, wherein the self adapting circuit means includes means (225,228) for automatically reducing the quiescent current for an output stage amplifier from one state of lower quiescent current to another state of higher quiescent current. 11. (Cancelled) 12. (Currently Amended) The device as claimed in Claim 7. A device including a radio frequency linear power amplifier operating in an output frequency band, having an output transistor, said power amplifier comprising: (a) a circuit means (300' for generating a bias signal producing a quiescent current flowing through said output transistor (42) of said RF power amplifier; (b) a detector circuit means (210) for detecting RF input to said amplifier and generating a driving signal (21.5) according to a power level of said RF input; (c) a self-adapting circuit means (250) for receiving said driving signal (215) and automatically modifying said bias signal and said quiescent current through said output transistor (O2), whereby said quiescent current at said output stage is adjusted for reduced dissipation and increased linearity at all power output levels; and turther comprising meuns (125, 126)

13. (Cancelled)

output stage under discrete voltage control.

(d) means (125,126) for further modifying said quiescent current at a second

14. (Cancelled)

15. (Currently Amended) The self-adapting circuit as elaimed in Claim 13.

A self-adapting circuit (250) for dynamically controlling quiescent current flowing through said output transistor of a linear power amplifier operating in an output frequency band, having an output transistor, said linear power amplifier comprising a circuit means (300') for generating a bias signal producing a quiescent current flowing through said output transistor of said RF power amplifier, said self-adapting bias circuit comprisine:

a) a detector circuit means (210) for detecting RF input to said amplifier and generating a driving signal (215) according to a power level of said RF input;
 b) means (225,228) for receiving said driving signal and automatically modifying said bias signal and said quiescent current through said output transistor, whereby said quiescent current at said output stage is adjusted for reduced dissipation and increased linearity at all power output levels; and

wherein the detector circuit means (210) for generating said driving signal (215) is connected to said modifying means (225), said detector circuit means (210) further including means (211,212) for filtering out any RF component of said driving signal.

16. (Currently Amended) The self-adapting circuit as claimed in Claim 13, The self-adapting circuit as claimed in Claim 15, wherein said circuit means for generating a bias signal producing a quiescent current comprises a differential transistor pair (325), said modifying means is connected to one side of said differential pair for automatically modifying said quiescent current for an output stage amplifier according to said detected RF signal input.

17. (Cancelled)

discrete voltage control.

18. (Currently Amended) The self-adapting circuit as claimed in Claim 13,

A self-adapting circuit (250) for dynamically controlling quiescent current flowing through said output transistor of a linear power amplifier operating in an output frequency band, having an output transistor, said linear power amplifier comprising a circuit means (300') for generating a bias signal producing a quiescent current flowing through said output transistor of said RF power amplifier, said self-adapting bias circuit comprising;

a) a detector circuit means (210) for detecting RF input to said amplifier and generating a driving signal (21 5) according to a power level of said RF input;

b) means (225,228) for receiving said driving signal and automatically modifying said bias signal and said quiescent current through said output transistor, whereby said quiescent current at said output stage is adjusted for reduced dissipation and increased linearity at all power output levels; and

wherein said second power output stage further includes means (125,

126) for further modifying said quiescent current at a second output stage under